

Superconductivity and Chemical Composition of the High- T_c Phase ($T_c \sim 111$ K) in the Sb-Pb-Bi-Sr-Ca-Cu-O System

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A superconducting phase with a critical temperature of 111 K in the Sb-Pb-Bi-Sr-Ca-Cu-O system has been synthesized by means of a long firing period. Its crystal structure is similar to the high- T_c phase (107 K) in the Pb-Bi-Sr-Ca-Cu-O system, and its average chemical composition is 4.3%, 2.6%, 19.2%, 21.4%, 15.8% and 36.9% for Sb, Pb, Bi, Sr, Ca and Cu, respectively. The summation of the Sb concentration and the Ca concentration is approximately the same for all the samples of this phase, implying that Sb substitutes for Ca, and oxygen atoms are introduced to compensate the oxygen deficiency in the central Cu-O layer sandwiched by the two Ca layers in the crystal structure of the high- T_c phase.

KEYWORDS: superconductor, Sb-Pb-Bi-Sr-Ca-Cu-O system, chemical composition, energy dispersive X-ray spectroscopy, electrical resistivity, magnetic susceptibility, X-ray powder diffraction

Since the discovery of the high- T_c superconductor in the Bi-Sr-Ca-Cu-O system,¹⁾ various dopants have been tried to increase the critical temperature. The addition of Pb has been confirmed to increase the volume fraction of the high- T_c phase ($T_c \sim 107$ K).²⁾ Recently, it has been reported that the samples with large amount of Pb have the critical temperatures above 110 K.* It has also been reported that the substitution of Sb and Pb for Bi in $\text{Bi}_2\text{Sr}_2\text{Ca}_2\text{Cu}_3\text{O}_x$ increases the endpoint critical temperature ($T_{c,\text{end}}$) to 132 K.³⁾ In addition, it has been reported that the substitution of only Sb for Bi also increases the $T_{c,\text{end}}$ to the same temperature.⁴⁾ Hongbao *et al.* have reported that they observed three jumps in diamagnetic signals around 90 K, 115–125 K and 135–140 K. They observed that the 135–140 K phase was so unstable that the temperature of zero resistance was decreased to 112 K after thermal cycling between 77 K and room temperature.

Many studies have been attempted to confirm the results about the Sb substitution. No research group except the above mentioned groups, however, has succeeded in obtaining a critical temperature above 110 K. The chemical compositions and the crystal structures of those phases having critical temperatures of 115–125 K and 135–140 K have not been reported yet. In order to clarify the chemical composition and the role of the Sb atom in the phases with T_c higher than 110 K, we studied the superconductivity and the chemical composition of the high- T_c phase in the Sb-Pb-Bi-Sr-Ca-Cu-O system.

A sample with nominal composition $\text{Sb}_{0.10}\text{Pb}_{0.50}\text{Bi}_{1.40}\text{Sr}_{2.00}\text{Ca}_{2.00}\text{Cu}_{3.00}\text{O}_x$ (sample A) was prepared by a solid-state reaction in air. The starting materials were high-purity powders of Sb_2O_3 , PbO , Bi_2O_3 , SrCO_3 , CaCO_3 and CuO . These powders were mixed, pressed into pellets, calcined at 820°C for 5 hours, fired at 865°C for 504 hours and then cooled at a rate of 50°C/h to room temperature. Another sample with nominal composition $\text{Pb}_{0.46}\text{Bi}_{1.80}\text{Sr}_{1.88}\text{Ca}_{2.06}\text{Cu}_{3.00}\text{O}_x$ (sample B) was prepared by a sol-gel process using citric salts to compare its superconducting response with sample A. The starting materials were high-purity powders of PbO , Bi_2O_3 , SrCO_3 , CaCO_3 and CuO , which were dissolved into nitric acid. The resulting solution was mixed with citric acid and ethylene glycol and then heated to obtain a blue gel. The gel thus obtained was calcined at 800°C for 30 minutes, ground, pressed into a pellet and fired at 850°C for 420 hours in air.

X-ray powder diffraction measurements were carried out using a Philips 1700 diffractometer with CuK_α radiation. Electrical resistivity was measured by the standard dc four-terminal method. Magnetic susceptibility was measured using a S.H.E. SQUID magnetometer in a magnetic field of 20 G.

For energy dispersive X-ray spectroscopy (EDS), the specimen was crushed, ground, dispersed in n-propanol and spread onto a holey carbon film suspended by a beryllium mesh grid. EDS was carried out for sample A using a JEM-200CX analytical electron microscope operated at 200 kV, equipped with a KeveX system 8000 spectrometer. In order to confirm that the observing parts of the specimen for EDS were superconducting crystals with no other phases, crystal forms and selected

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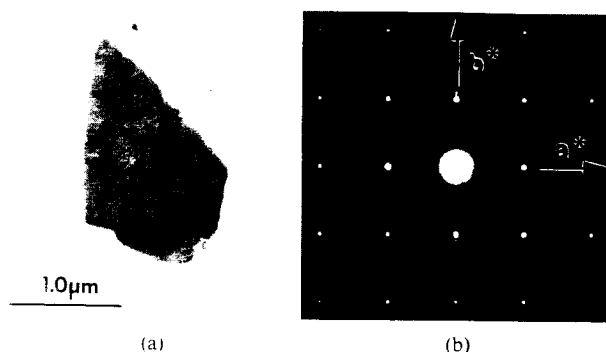


Fig. 1. A typical crystal form (a) of the superconducting crystal chosen for EDS and its selected area electron diffraction pattern with the incident beam along the [001] zone axis (b). Superconducting crystals having the plate-like morphology with small thicknesses were chosen for EDS. The high- T_c phase with Sb has a modulated structure with b -axis wavelengths 26.9 Å and 36.1 Å. The corresponding satellite spots are observed in the selected area electron diffraction pattern.

area electron diffraction patterns were observed. Figure 1 shows a typical crystal form of the superconducting crystal chosen for EDS and its selected area electron diffraction pattern. Superconducting crystals having the plate-like morphology with small thicknesses like Fig. 1(a) were chosen for EDS. The high- T_c phase with Sb has a modulated structure with b -axis wavelengths 26.9 Å and 36.1 Å like Fig. 1(b) as reported by the authors.* On the other hand, the high- T_c phase without Sb has a modulated structure with b -axis wavelengths 27 Å and 45–54 Å. The chemical composition of the each crystal was calculated by the deconvolution procedure with the intensities of the SbL_α , PbL_α , BiL_α , SrK_α , CaK_α and CuK_α radiations.

The microstructures of the samples were observed by means of a JXA-8600 electron probe microanalyser (EPMA) operated at 15 kV. For this analysis, the fired samples were wet-polished and deposited with carbon. The chemical compositions were calculated by the Z-A-F correction method on the basis of the data which were measured by the wavelength dispersive X-ray analysis.

Figure 2 shows the temperature dependence of the electrical resistivity of samples A and B. The $T_{c,\text{end}}$ of sample A is 110 K, which is 5 K higher than that of sample B. The $T_{c,\text{mid}}$ of sample A is 112 K, which is 5 K higher than that of sample B. Note that a decrease in the electrical resistivity about 132 K is not observed; nevertheless, an increase of 5 K in critical temperature is apparently observed for the Sb-containing sample (sample A). The difference between the two critical temperatures is not within the error of the temperature measurement.

Figure 3 shows the temperature dependence of the magnetic susceptibility of both samples. Diamagnetism is observed below 111.3 K for sample A and 107.3 K for sample B, showing that sample A has a 4 K higher critical temperature than sample B. These results imply that Sb substitutes some of the atomic positions in the superconducting crystal and affects the superconductivity.

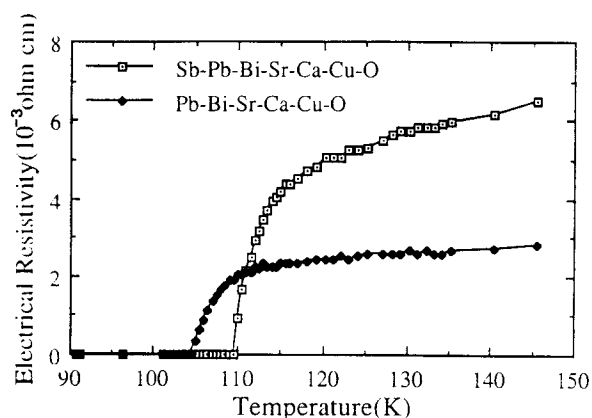


Fig. 2. Temperature dependence of the electrical resistivity of the superconductors in the Sb-Pb-Bi-Sr-Ca-Cu-O system (sample A) and the Pb-Bi-Sr-Ca-Cu-O system (sample B). The $T_{c,\text{end}}$ of sample A and that of sample B are 110 K and 105 K, respectively.

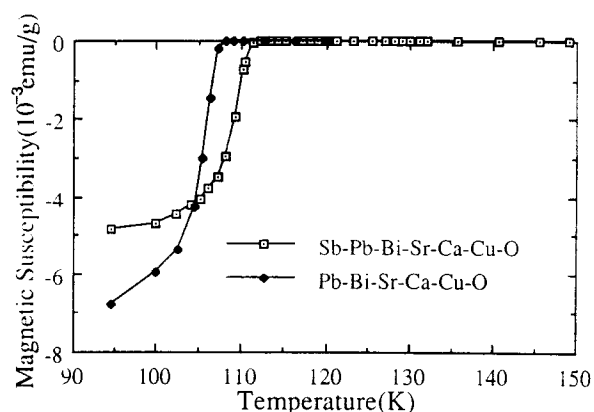


Fig. 3. Temperature dependence of the magnetic susceptibility of the superconductors in the Sb-Pb-Bi-Sr-Ca-Cu-O system (sample A) and the Pb-Bi-Sr-Ca-Cu-O system (sample B). The T_c of sample A is 111.3 K and that of sample B is 107.3 K.

Hongbao *et al.*³⁾ reported that there are two stable superconducting phases with critical temperatures of 90 K and 115–125 K in this system. Based upon our data, the superconductor synthesized in this research appears to be the same as one of the superconducting phases that they synthesized in the same system.

Figure 4 shows the X-ray powder diffraction patterns of sample A and sample B. The diffraction pattern of sample A is similar to that of sample B except for peaks around 30° in 2θ and other minor peaks. The low- T_c phase ($T_c \sim 80$ K) is not observed in either of the diffraction patterns. The data show that the high- T_c phase ($T_c \sim 107$ K) is the sole precipitate in sample B without any other phases. Since the diffraction pattern of sample A consists of the same peaks as the high- T_c phase in the diffraction pattern of sample B, the crystal structure of the superconducting phase in sample A appears to be close to that of the high- T_c phase in the Pb-Bi-Sr-Ca-Cu-O system. If we assume that the superconducting crystal in sample A belongs to the orthorhombic system, the lattice parameters are $a = 5.411(1)$ Å, $b = 5.411(1)$ Å and $c = 37.22(6)$ Å, which are close to those of the high- T_c phase (107 K) in the Pb-Bi-Sr-Ca-Cu-O system⁵⁾ ex-

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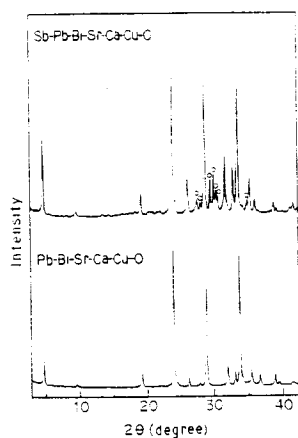


Fig. 4. X-ray powder diffraction patterns of the superconductors in the Sb-Pb-Bi-Sr-Ca-Cu-O system and the Pb-Bi-Sr-Ca-Cu-O system. Diffraction peaks from impurities are marked (O).

cept for the slightly longer c -axis parameter. Even though the atomic radius of the Sb^{3+} ion is smaller than that of the other ions in the system, the cell volume of the high- T_c phase ($T_c \sim 111$ K) in the Sb-Pb-Bi-Sr-Ca-Cu-O system is close to that in the Pb-Bi-Sr-Ca-Cu-O system.

In order to determine the mean value of the chemical composition of the high- T_c phase ($T_c \sim 111$ K), several EDS measurements were carried out for many crystals in sample A. Figure 5 shows the atomic concentrations of 17 superconducting crystals within sample A. The atomic concentrations of Pb, Bi, Sr and Cu are nearly the same for all the crystals; however, the atomic concentrations of Sb and Ca in the crystals from No. 1 to No. 4 are slightly different than those from No. 5 to No. 17. The crystals from No. 5 to No. 17 (Sb-rich crystals) have more Sb and less Ca than the crystals from No. 1 to No. 4 (Sb-poor crystals). Significantly, as the Sb concentration is increased, the Ca concentration is decreased. Furthermore since the sum of the Sb concentration and the Ca concentration is the same (or very nearly so) for all the crystals, it is suggested that Sb substitutes for Ca in the crystal. The results are not coincident with those analyzed with EDS by Xu *et al.*⁶¹ They concluded that Sb cannot be doped

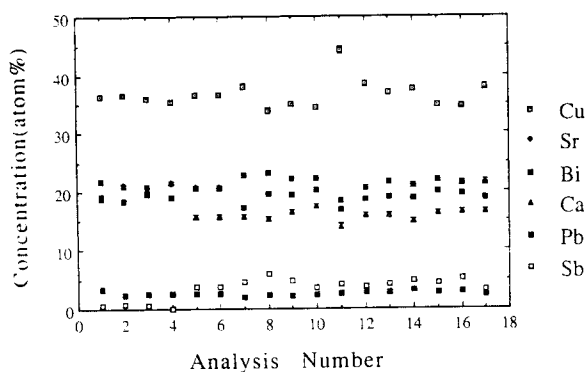


Fig. 5. Atomic concentrations of the superconducting phase in the Sb-Pb-Bi-Sr-Ca-Cu-O system determined by energy dispersive X-ray spectroscopy. Error bars attached to the marks have almost the same height as the marks themselves. Note that the summation of the Sb concentration and the Ca concentration is nearly the same for all the crystals.

into the high- T_c phase but goes into a new phase with the average composition $Bi_{32}Pb_3Sb-Sr_{29}Ca_{23}Cu_7O_x$. This phase is considered identical with an amorphous-like phase with the composition $Sb_{0.5}Bi_{2.0}Sr_{1.6}Ca_{1.0}Cu_{0.4}O_x$ observed in sample A as mentioned below. Since the modulated structure of the high T_c phase in the Sb-Pb-Bi-Sr-Ca-Cu-O system is different than that in Pb-Bi-Sr-Ca-Cu-O system, Sb may occupy some of the atomic sites in the high- T_c phase.

As for the measurements of the chemical composition by EDS, we observed the intensities of SbL_{α} and CaK_{α} radiations of which X-ray energies (SbL_{α} : 3.605 keV and CaK_{α} : 3.691 keV, respectively) are close to each other as shown in Fig. 6. Since crystal No. 13 contains more Sb than crystal No. 3, the width of the peak about 3.7 keV of spectrum 13 in Fig. 6(b) is much broader than that of spectrum 3 in Fig. 6(a) because of the overlapping of the SbL_{α} and CaK_{α} radiations. The deconvolution curves for SbL_{α} and CaK_{α} radiations are clearly obtained for Sb-rich crystal No. 13 in Fig. 6(b); however, the Sb concentration of the Sb-poor crystal is too small to determine the Sb concentration by the deconvolution method as shown in Fig. 6(a).

Table I shows the mean values of the chemical compositions of Sb-rich crystals and Sb-poor crystals in the Sb-Pb-Bi-Sr-Ca-Cu-O system. Those in the Pb-Bi-Sr-Ca-Cu-O system are also shown in the table to compare the difference in the chemical compositions of the high- T_c phases between the two systems. The chemical compositions of the high- T_c phase in the Pb-Bi-Sr-Ca-Cu-O system were obtained previously.⁵¹ The chemical composition of the Sb-poor crystal is very close to the chemical composition of the high- T_c phase in the Pb-Bi-Sr-Ca-

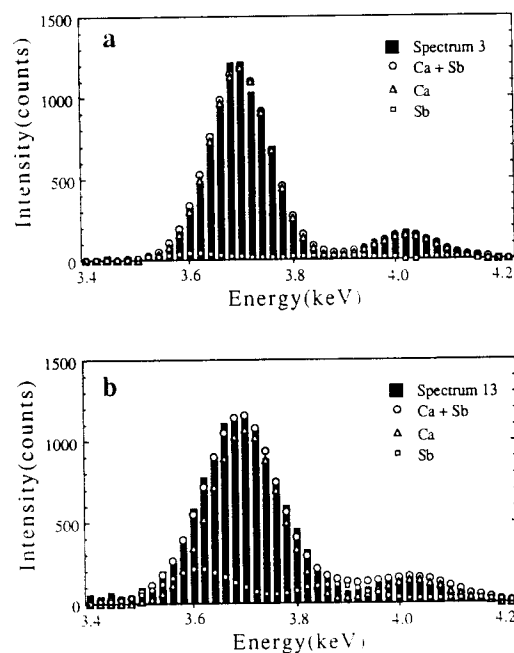


Fig. 6. Energy dispersive X-ray spectra and the deconvolution curves for Sb (\square), Ca (\triangle) and the sum of Sb and Ca (\circ) for crystals No. 3 (a) and No. 13 (b). Since crystal No. 13 contains more Sb than crystal No. 3, the width of the peak about 3.7 keV of spectrum 13 is much broader than that of spectrum 3 because of the overlapping of the SbL_{α} and CaK_{α} radiations.

Table I. Chemical compositions of the superconducting phases in the Sb-Pb-Bi-Sr-Ca-Cu-O system analyzed by Energy Dispersive X-ray Spectroscopy and in the Pb-Bi-Sr-Ca-Cu-O system analyzed by Wavelength Dispersive X-ray Spectroscopy (WDS) and Rietveld analysis of X-ray powder diffraction data.

	Sb-Pb-Bi-Sr-Ca-Cu-O		Pb-Bi-Sr-Ca-Cu-O	
	Sb-rich phase (atom%)	Sb-poor phase (atom%)	WDS (atom%)	Rietveld analysis (atom%)
Sb	4.3(0.7)	[0.5]	—	—
Pb	2.6(0.3)	2.7(0.4)	3.7(0.2)	4.2(0.2)
Bi	19.2(1.2)	19.1(0.5)	19.9(0.2)	20.3(0.4)
Sr	21.4(1.2)	21.3(0.4)	20.4(0.9)	20.7(0.3)
Ca	15.8(0.9)	20.4(1.2)	20.9(0.3)	21.4(0.3)
Cu	36.9(2.7)	36.1(0.5)	35.1(0.3)	33.3

Cu-O system determined by wavelength dispersive X-ray spectroscopy (WDS) coupled with Rietveld analysis, suggesting that the Sb-poor crystal may be identical to the high- T_c phase of the Pb-Bi-Sr-Ca-Cu-O system. On the other hand, the Sb-rich crystal (4.3 atom%) has less Ca. Takada *et al.* reported that the superconducting materials with compositions $(\text{Bi}_{1-\alpha}\text{Pb}_\alpha)_n\text{Sr}_{1.0}\text{Ca}_{1.0}\text{Cu}_y\text{O}_x$, where $0.26 \leq \alpha \leq 0.36$, $n=1.1$ and 1.2 , and $1.50 \leq y \leq 1.80$, have the critical temperatures above 110 K. Since both Sb-poor phase and Sb-rich phase have much less Pb than their samples, the reason why sample A has the critical temperature of 111 K is different than the large amount of Pb doped in their samples. As the high- T_c phase with less Pb in the Pb-Bi-Sr-Ca-Cu-O system has a critical temperature of 107 K, the Sb-poor crystal probably does not contribute to increase the critical temperature to 111 K. Rather, the Sb-rich crystal is the one with a critical temperature of 111 K.

There are two Ca layers sandwiched by the Cu-O layers in the high- T_c phase ($T_c \sim 107$ K) of the Pb-Bi-Sr-Ca-Cu-O system. If trivalent Sb occupies a fraction of the divalent Ca sites in the high- T_c phase ($T_c \sim 111$ K) of the Sb-Pb-Bi-Sr-Ca-Cu-O system, more oxygen atoms will have to be introduced into the Cu-O layers to compensate for charge imbalance. With a high resolution electron microscope, Hetherington *et al.*⁷⁾ observed some amount of oxygen deficiency in the central Cu-O layer of the high- T_c phase of the Pb-Bi-Sr-Ca-Cu-O system. If more oxygen atoms can be introduced as a result of the substitution of Sb for Ca, it might be possible to make up

for this oxygen deficiency and to affect the electronic state of the central Cu-O layer to increase the critical temperature from 107 K to 111 K.

The reason why there are both Sb-rich and Sb-poor phases in the same specimen may be due to the inhomogeneous mixing of the raw powders. More homogeneous mixing like that resulting from the sol-gel process is preferable. Large amount of impurities with chemical compositions of $\text{Sr}_{0.2}\text{Ca}_{1.9}\text{Cu}_{1.0}\text{O}_x$, $\text{Sr}_{1.0}\text{Ca}_{0.8}\text{Cu}_{3.0}\text{O}_x$ and $\text{Sb}_{0.5}\text{Bi}_{2.0}\text{Sr}_{1.6}\text{Ca}_{1.0}\text{Cu}_{0.4}\text{O}_x$, were observed with small amount of the superconducting phase in sample A by EPMA.

In conclusion, a superconducting phase with a critical temperature of 111 K in the Sb-Pb-Bi-Sr-Ca-Cu-O system has been synthesized using a long firing period. Its orthorhombic lattice parameters are $a=5.411(1)$ Å, $b=5.411(1)$ Å and $c=37.22(6)$ Å. The average chemical composition of the phase with the 111 K critical temperature is 4.3%, 2.6%, 19.2%, 21.4%, 15.8% and 36.9% for Sb, Pb, Bi, Sr, Ca and Cu, respectively. It is implied that Sb substitutes for Ca in the lattice, requiring that excess oxygen is introduced to compensate for the oxygen deficiency in the central Cu-O layer of the structure. It may be this Sb substitution for Ca that increases the critical temperature from 107 K to 111 K.

Acknowledgments

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